
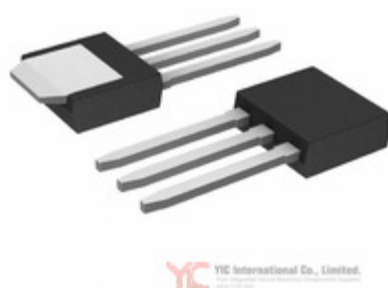
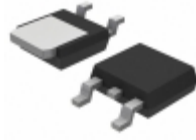


	<h2>NTD2955-1G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTD2955-1G</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 60V 12A IPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD2955-1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 12186 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTD2955-1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET P-CH 60V 12A IPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	12186 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	55W (Tj)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12A (Ta)
Rds On (Max) @ Id, Vgs	180 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube


















































NTD2955-1G ist neu im Original, Suche NTD2955-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD2955-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD2955-1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTD2955-1</b> AMI Semiconductor / ON Semiconductor NTD2955-1 ON</p>	 <p><b>NTD25P06LT4G</b> O NTD25P06LT4G O</p>	 <p><b>NTD2955PT4G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 12A DPAK</p>	 <p><b>NTD2955-001</b> VB NTD2955-001 VB</p>
 <p><b>NTD2955E</b> O NTD2955E O</p>	 <p><b>NTD2955</b> ON NTD2955 ON</p>	 <p><b>NTD2955G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 12A DPAK</p>	 <p><b>NTD25P03LT4G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 25A DPAK</p>

### heiße Teile

Mehr

 NTD23N03RT4	 NTD23N03RT4G	 NTD24N06	 NTD24N06-1G	 NTD24N06G
 NTD24N06L	 NTD24N06L-001	 NTD24N06L-1G	 NTD24N06L4T	 NTD24N06LG
 NTD24N06LT4	 NTD24N06LT4G	 NTD24N06T4	 NTD24N06T4G	 NTD25N06HL
 NTD25P03	 NTD25P03L	 NTD25P03L-1	 NTD25P03L1G	 NTD25P03LG
 NTD25P03LRLG	 NTD25P03LT4G	 NTD25P06LT4G	 NTD2955-001	 NTD2955-1
 NTD2955D	 NTD2955E	 NTD2955G	 NTD2955PT4G	 NTD2955T4
 NTD2955T4G	 NTD2955V	 NTD2955VT4G	 NTD3055-094	 NTD3055-094-1G
 NTD3055-094G	 NTD3055-094T4	 NTD3055-094T4G	 NTD3055-150	 NTD3055-150-1G
 NTD3055-150G	 NTD3055-150T4	 NTD3055-150T4G	 NTD3055-170T4G	 NTD3055L104T4G
 NTD3055L	 NTD3055L04T4G	 NTD3055L104	 NTD3055L104-1G	 NTD3055L104G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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